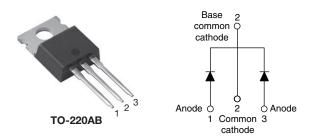
Vishay Semiconductors

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PRIMARY CHARACTERISTICS								
I _{F(AV)} 2 x 15 A								
V _R	80 V							
V _F at I _F	0.67 V							
I _{RM} max.	7.0 mA at 125 °C							
T _J max.	175 °C							
E _{AS}	7.50 mJ							
Package	TO-220AB							
Circuit configuration	Common cathode							

FEATURES

- 175 °C T_J operation
- Low forward voltage drop
- High frequency operation
- High purity, high temperature epoxy encapsulation for enhanced mechanical strength and moisture resistance



- Guard ring for enhanced ruggedness and long term reliability
- AEC-Q101 qualified, meets JESD 201, class 2 whisker test
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>

DESCRIPTION

The center tap Schottky rectifier series has been optimized for low reverse leakage at high temperature. The proprietary barrier technology allows for reliable operation up to 175 °C junction temperature. Typical applications are in switching power supplies, converters, freewheeling diodes, and reverse battery protection.

MAJOR RATINGS AND CHARACTERISTICS								
SYMBOL CHARACTERISTICS VALUES								
I _{F(AV)}	Rectangular waveform	30	А					
V _{RRM}		80	V					
I _{FSM}	$t_p = 5 \ \mu s \ sine$	850	А					
V _F	15 A_{pk} , T_J = 125 °C (per leg)	0.67	V					
TJ	Range	-55 to +175	°C					

VOLTAGE RATINGS							
PARAMETER	SYMBOL	VS-30CTQ080HN3	UNITS				
Maximum DC reverse voltage	V _R	80	V				
Maximum working peak reverse voltage	V _{RWM}	80	v				

ABSOLUTE MAXIMUM RATINGS								
PARAMETER	SYMBOL	TEST COND	TEST CONDITIONS					
Maximum average forward per device	I	50 % duty cyclo at $T_{-} = 120$ %	rootangular wayoform	30	^			
current, see fig. 5 per leg	I _{F(AV)}	50 % duty cycle at T_C = 129 °C, rectangular waveform		15	A			
Maximum peak one cycle non-repetitive	I _{FSM}	5 μs sine or 3 μs rect. pulse	Following any rated load condition and with rated	850	А			
surge current per leg, see fig. 7		10 ms sine or 6 ms rect. pulse	V _{RRM} applied	275				
Non-repetitive avalanche energy per leg	E _{AS}	T _J = 25 °C, I _{AS} = 0.50 A, L = 60 mH		7.50	mJ			
Repetitive avalanche current per leg	betitive avalanche current per leg I_{AR} Current decaying linearly to zero in 1 µs Frequency limited by T _J maximum V _A = 1.5 x V _R typical			0.50	А			

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ELECTRICAL SPECIFICATIONS
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ELECTRICAL SPECIFICATIONS								
PARAMETER	SYMBOL	TEST CO	VALUES	UNITS				
Maximum forward voltage drop per leg See fig. 1		15 A	T.I = 25 °C	0.86				
	V (1)	30 A	1j=25 C	1.05	V			
	V _{FM} ⁽¹⁾	15 A	T.I = 125 °C	0.67	v			
		30 A	1j = 125 C	0.82				
Maximum reverse leakage current per leg	I _{RM} ⁽¹⁾	T _J = 25 °C	$V_{\rm B}$ = Rated V _B	0.55	mA			
See fig. 2		T _J = 125 °C	VR = haleu VR	7.0				
Maximum junction capacitance per leg	CT	$V_{R} = 5 V_{DC}$ (test signal range 100 kHz to 1 MHz) 25 °C		500	pF			
Typical series inductance per leg	L _S	Measured lead to lead 5 m	8.0	nH				
Maximum voltage rate of change	dV/dt	Rated V _R	10 000	V/µs				

Note

 $^{(1)}\,$ Pulse width < 300 $\mu s,$ duty cycle < 2 %

THERMAL - MECHAN	THERMAL - MECHANICAL SPECIFICATIONS									
PARAMETER		SYMBOL	TEST CONDITIONS	VALUES	UNITS					
Maximum junction and storage temperature range		T _J , T _{Stg}		-55 to +175	°C					
Maximum thermal resistance, junction to case per leg Maximum thermal resistance, junction to case per package				3.25						
		R _{thJC}	DC operation	1.63	°C/W					
Typical thermal resistance, case to heatsink		R _{thCS}	Mounting surface, smooth, and greased	0.50						
Approximate weight				2	g					
Approximate weight				0.07	oz.					
Mounting torque	minimum			6 (5)	kgf ⋅ cm					
Mounting torque	maximum			12 (10)	(lbf ⋅ in)					
Marking device			Case style TO-220AB	30CTC	Q080H					



VS-30CTQ080HN3

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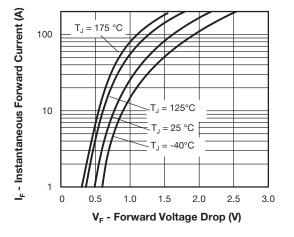


Fig. 1 - Maximum Forward Voltage Drop Characteristics (Per Leg)

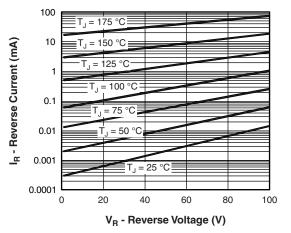


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage (Per Leg)

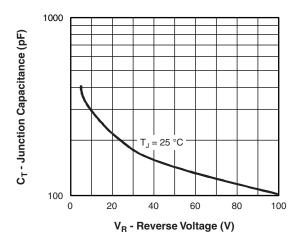
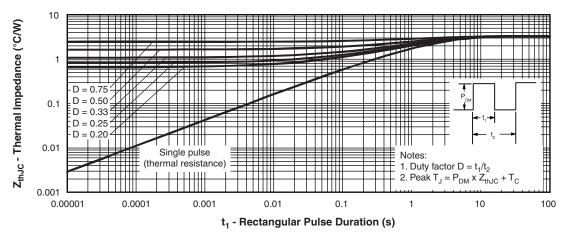
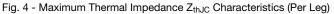


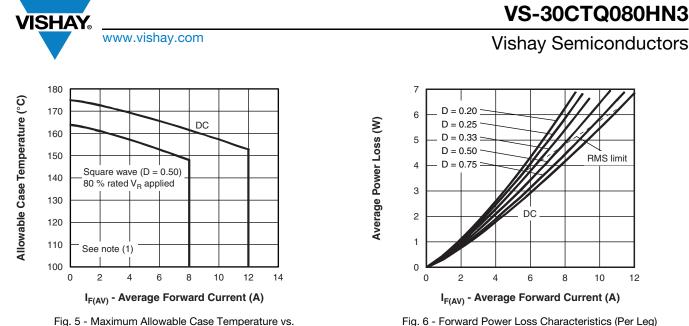
Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage (Per Leg)

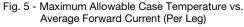


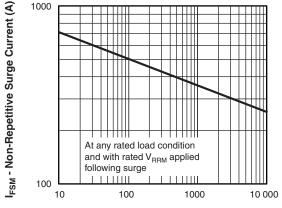


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t_p - Square Wave Pulse Duration (μs)

Fig. 7 - Maximum Non-Repetitive Surge Current (Per Leg)

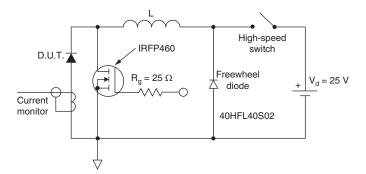


Fig. 8 - Unclamped Inductive Test Circuit

Note

- Formula used: $T_C = T_J (Pd + Pd_{REV}) \times R_{thJC}$; (1)
- $\begin{array}{l} \mathsf{Pd} = \mathsf{forward} \ \mathsf{power} \ \mathsf{loss} = \mathsf{I}_{\mathsf{F}(\mathsf{AV})} \times \mathsf{V}_{\mathsf{FM}} \ \mathsf{at} \ (\mathsf{I}_{\mathsf{F}(\mathsf{AV})} / \mathsf{D}) \ (\mathsf{see} \ \mathsf{fig.} \ \mathsf{6}); \\ \mathsf{Pd}_{\mathsf{REV}} = \mathsf{inverse} \ \mathsf{power} \ \mathsf{loss} = \mathsf{V}_{\mathsf{R1}} \times \mathsf{I}_{\mathsf{R}} \ (\mathsf{1} \mathsf{D}); \ \mathsf{I}_{\mathsf{R}} \ \mathsf{at} \ \mathsf{V}_{\mathsf{R1}} = \mathsf{10} \ \mathsf{V} \end{array}$

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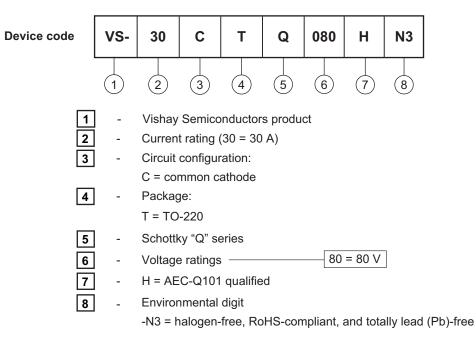
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ORDERING INFORMATION TABLE



ORDERING INFORMATION (Example)									
PREFERRED P/N QUANTITY PER T/R MINIMUM ORDER QUANTITY PACKAGING DESCRIPTION									
VS-30CTQ080HN3	50	1000	Antistatic plastic tube						

LINKS TO RELATED DOCUMENTS						
Dimensions www.vishay.com/doc?95222						
Part marking information	www.vishay.com/doc?95028					

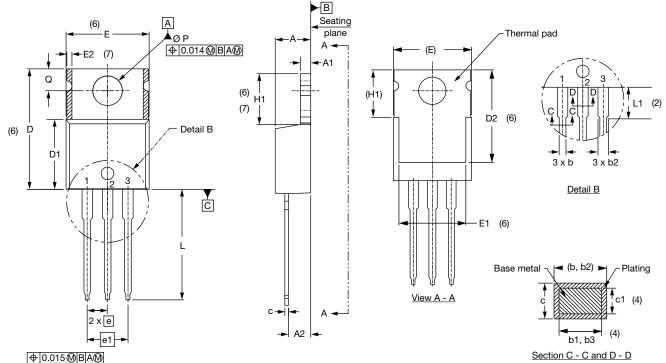
Outline Dimensions



Vishay Semiconductors

TO-220AB

DIMENSIONS in millimeters and inches



Lead tip

Conforms to JEDEC[®] outline TO-220AB

SYMBOL	MILLIMETERS		INCHES		NOTES SY	SYMBOL	MILLIMETERS		INCHES		NOTES	
STIVIDUL	MIN.	MAX.	MIN.	MAX.	NOTES		STWIDOL	MIN.	MAX.	MIN.	MAX.	NULES
А	4.25	4.65	0.167	0.183			D2	11.68	12.88	0.460	0.507	6
A1	1.14	1.40	0.045	0.055			Е	10.11	10.51	0.398	0.414	3, 6
A2	2.56	2.92	0.101	0.115			E1	6.86	8.89	0.270	0.350	6
b	0.69	1.01	0.027	0.040			E2	-	0.76	-	0.030	7
b1	0.38	0.97	0.015	0.038	4		е	2.41	2.67	0.095	0.105	
b2	1.20	1.73	0.047	0.068			e1	4.88	5.28	0.192	0.208	
b3	1.14	1.73	0.045	0.068	4		H1	5.84	6.86	0.230	0.270	6, 7
с	0.36	0.61	0.014	0.024			L	13.52	14.02	0.532	0.552	
c1	0.36	0.56	0.014	0.022	4		L1	3.32	3.82	0.131	0.150	2
D	14.85	15.25	0.585	0.600	3		ØР	3.54	3.73	0.139	0.147	
D1	8.38	9.02	0.330	0.355			Q	2.60	3.00	0.102	0.118	

Notes

⁽¹⁾ Dimensioning and tolerancing as per ASME Y14.5M-1994

⁽²⁾ Lead dimension and finish uncontrolled in L1

(3) Dimension D, D1 and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outermost extremes of the plastic body

(4) Dimension b1, b3 and c1 apply to base metal only

⁽⁵⁾ Controlling dimensions: inches

⁽⁶⁾ Thermal pad contour optional within dimensions E, H1, D2 and E1

⁽⁷⁾ Dimensions E2 x H1 define a zone where stamping and singulation irregularities are allowed

(8) Outline conforms to JEDEC[®] TO-220, except A2 (maximum) and D2 (minimum) where dimensions are derived from the actual package outline

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